

Lead (Pb) Free Product - RoHS Compliant

L1300/1450/1550/PD-35B32

L1300/1450/1550/PD-B32 consists of an InGaAs and an InGaAs PD mounted on TO-18 stem with a spherical glass lens, and is designed to moniter reflected light through detector for controlling its own output power.

◆Specifications

1) Product Name Multi-wavelength LED Lamp 2) Type No. L1300/1450/1550/PD-35B32

3) Chip

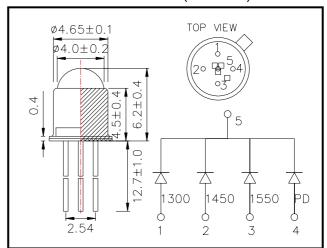
(1) Chip material InGaAs(LED, PD)(2) Peak wavelength 1300, 1450 and 1550nm

4) Package

(1) Stem TO-18 5pin type
(2) Lens Φ5mm spherical glass

multi-wavelength LED

♦ Outer dimension (Unit: mm)



◆Absolute Maximum Ratings/ per each one chip [Ta=25°C]

Device	Item	Symbol	Max	Unit		
	item		1300	1450	1550	Offic
LED	Power Dissipation	PD	120	120	120	mW
LED	Forward Current	lF	100	100	100	mA
LED	Pulse Forward Current	lF	1000	1000	1000	mA
LED	Reverse Voltage	VR		V		
PD	Reverse Voltage	VR	10			V
Topr	Operating Temperature	Topr	-20 ~ +80			°C
Tstg	Storage Temperature	Tstg		-30 ~ +100		°C
Tsol	Soldering Temperature	Tsol		240		°C

‡Soldering condition: Soldering condition must be completed within 3 seconds at 240°C and is allowed in the area apart 3mm from the bottom of the lamp.

◆ Electro-Optical Characteristics/ per each one chip [Ta=25°C]

Device	Item	Wavelength	Condition	Minimum	Typical	Maximum	Unit
LED	Forward Voltage	1300	IF=20mA		0.8	1.3	V
		1450			0.8	1.3	
		1550			0.8	1.3	
	Reverse Current		VR=5V			10	uA
	Total Radiated Power	1300	IF=20mA		1.3		mW
		1450			1.0		
		1550			8.0		
	Peak Wavelength	1300	IF=20mA	1250	1300	1350	nm
		1450		1400	1450	1500	
		1550		1500	1550	1600	
	Half Width	1300	IF=20mA		75		nm
		1450			75		
		1550			75		
PD	Output Current	1300	IF=20mA VR=0V		45		uA
		1450			35		
		1550	VK-0V		35		
	Dark Current		VR=10V]		100	nA

‡Total Radiated Power is measured by Photodyne #500

‡Radiated Power of NIR LED are measured by Ando Optical Multi Meter AQ2140 & AQ2742